

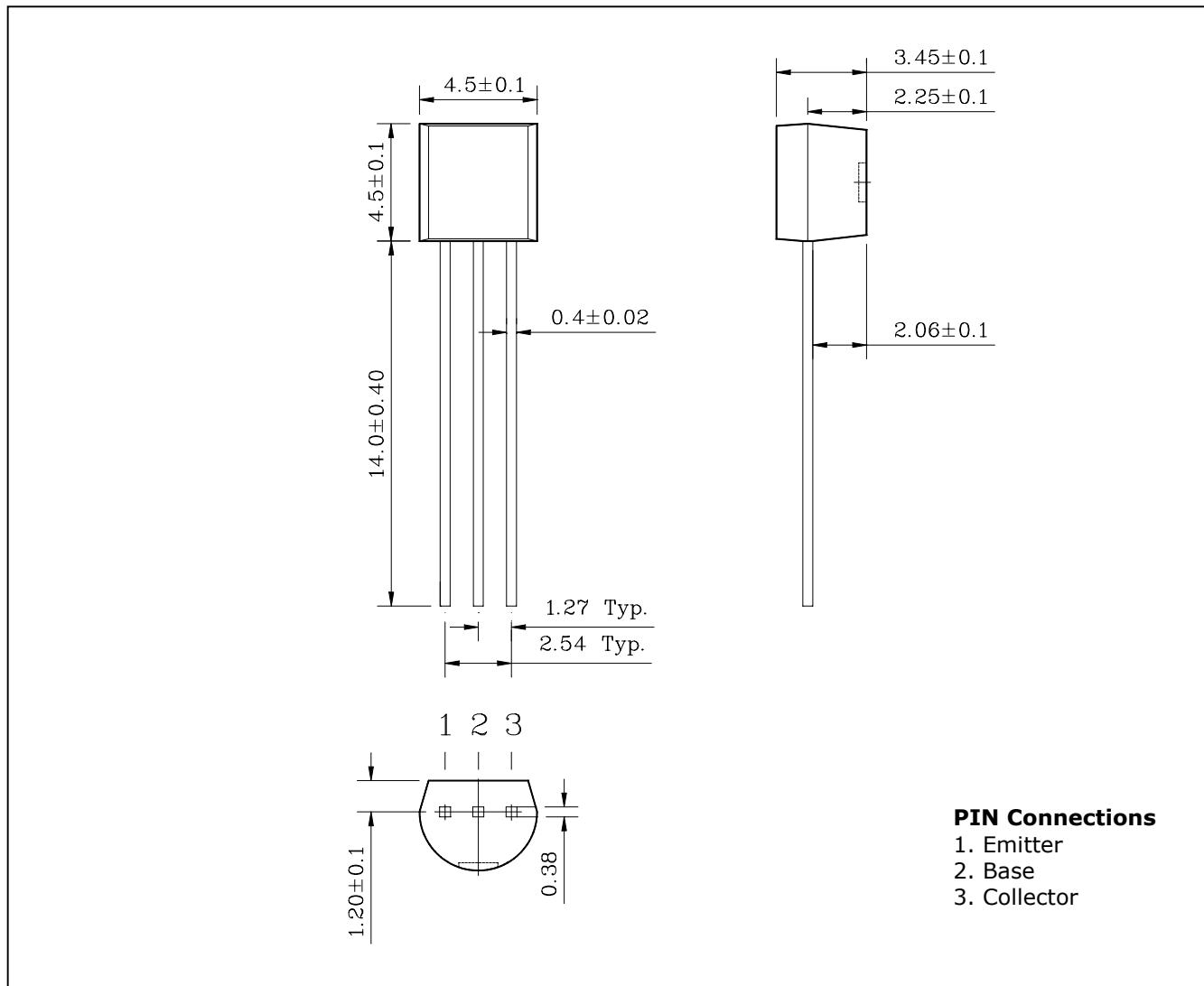
## Features

- Low saturation medium current application
- Extremely low collector saturation voltage
- Suitable for low voltage large current drivers
- High DC current gain and large current capability
- Low on resistance :  $R_{ON}=0.6\Omega$ (Max.) ( $I_B=1mA$ )

## Ordering Information

Type NO.	Marking	Package Code
STD123	STD123	TO-92

## Outline Dimensions

**unit : mm**


**Absolute maximum ratings**

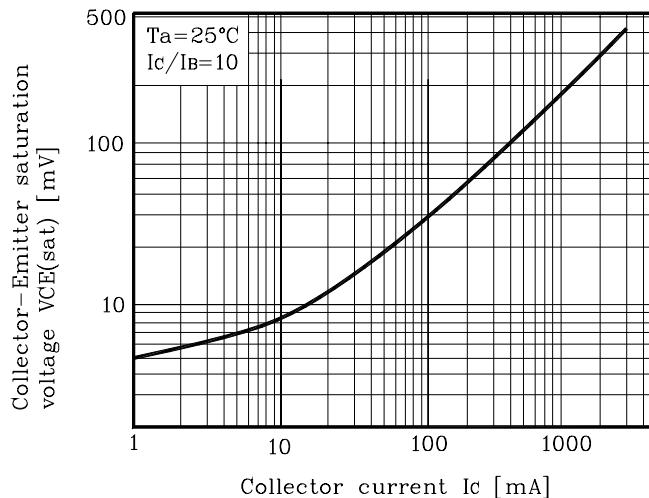
<b>Characteristic</b>	<b>Symbol</b>	<b>Ratings</b>	<b>Unit</b>
Collector-Base voltage	$V_{CBO}$	20	V
Collector-Emitter voltage	$V_{CEO}$	15	V
Emitter-base voltage	$V_{EBO}$	6.5	V
Collector current	$I_C$	1	A
Collector dissipation	$P_C$	625	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55~150	°C

**Electrical Characteristics**

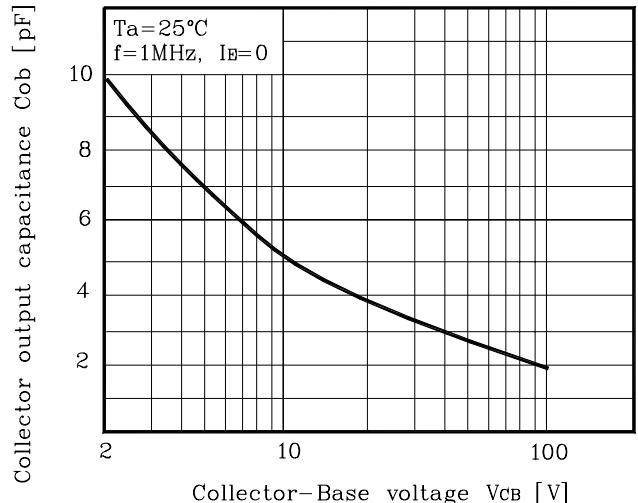
<b>Characteristic</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Collector-base breakdown voltage	$BV_{CBO}$	$I_C=50\mu A, I_E=0$	20	-	-	V
Collector-Emitter breakdown voltage	$BV_{CEO}$	$I_C=1mA, I_B=0$	15	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	$I_E=50\mu A, I_C=0$	6.5	-	-	V
Collector cut-off current	$I_{CBO}$	$V_{CB}=20V, I_E=0$	-	-	0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=6V, I_C=0$	-	-	0.1	$\mu A$
DC current gain	$h_{FE}$	$V_{CE}=1V, I_C=100mA$	150	-	-	-
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=500mA, I_B=50mA$	-	0.1	0.3	V
Transistor frequency	$f_T$	$V_{CE}=5V, I_C=50mA$	-	260	-	MHz
Collector output capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0, f=1MHz$	-	5	-	pF
On resistance	$R_{ON}$	$f=1KHz, I_B=1mA, V_{IN}=0.3V$	-	0.6	-	$\Omega$

## Electrical Characteristic Curves

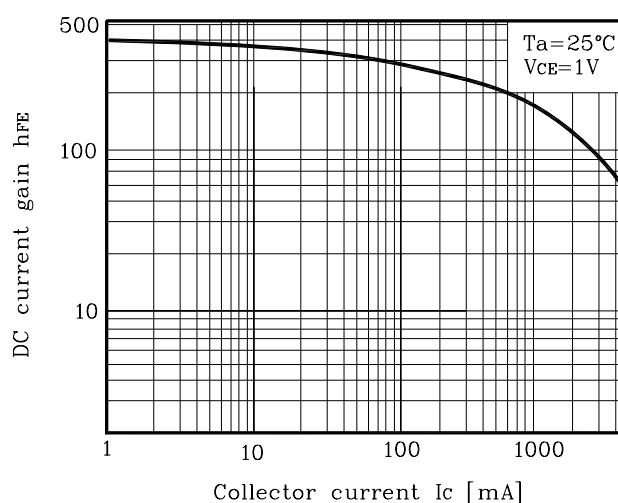
**Fig. 1  $V_{CE(sat)}$ - $I_C$**



**Fig. 1  $C_{Ob}$ - $V_{CB}$**



**Fig. 3  $h_{FE}$ - $I_C$**



**Fig. 4  $R_{ON}$ - $I_B$**

